

GL3T422 / GL3T421

**8.0mm Character Height
Numeric LEDs**

■ Model No.

GL3T422/GL3T421

Red (High-luminosity)

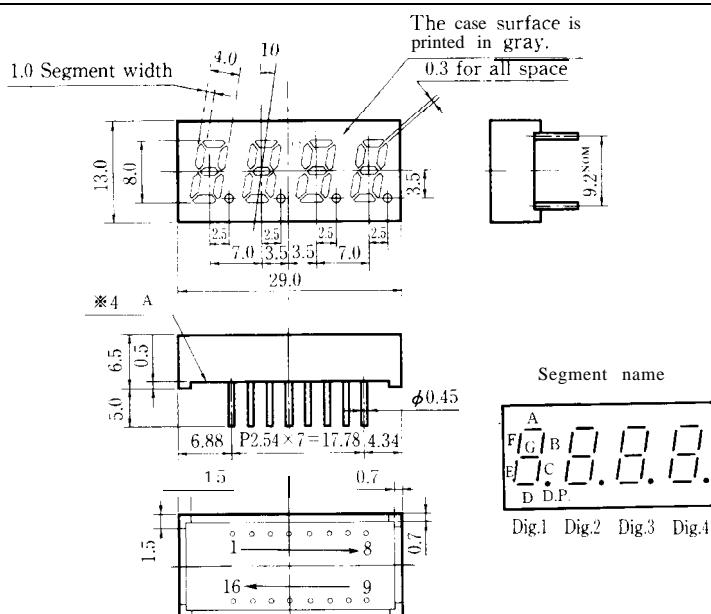
GaAlAs/GaAs

■ Features

1. Character height : 8.0mm
2. 4 digits
3. Case mold type
4. Diamond cut type segments

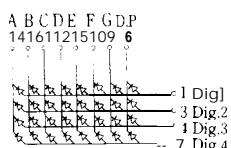
■ Outline Dimensions

(Unit: mm)

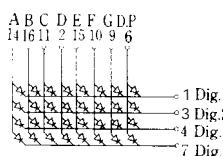


Internal connection diagram

GL3T422



GL3T421



Unspecified tolerance: ±0.38mm

SHARP

In the absence of confirmation by device specificationsheets, SHARP takes no responsibility for any defects that occur in environments using any of SHARP's devices, shown in catalogs, data books, etc. Contact SHARP in Order to obtain the latest version of the device specification sheets before using any SHARP's device.

GL3T422/GL3T421

■ Absolute Maximum Ratings

(Ta=25°C)

Parameter	Symbol	GL3T422						Unit
		GL3T421						
Power dissipation	*1 Per digit	P	308					mW
Continuous forward current	*1 Per digit	I _F	140					mA
	*2	I _F	20					mA
*3 Peak forward current	*2	I _{FM}	100					mA
Derating factor	*2	DC	—	0.36				mA/°C
		Pulse	—	1.82				mA/°C
Reverse voltage	Per segment	V _R	5					v
	Per decimal point	V _R	5					V
Operating temperature	T _{opr}			30 to +70				'c
Storage temperature	T _{stg}			-40 to +80				"c
*4 Soldering temperature	T _{sol}			260 (within 5 seconds)				'c

*1 Per digit: 7 segments

*2 Per segment, or per decimal point

*3 Duty ratio = 1/10, Pulse width = 0.1ms

*4 At the position of 2.1 mm from ③ level of outline dimensions

GL3T422/GL3T421(Red)**Electro-optical Characteristics**

(Ta = 25°C)

Parameter	Symbol	Model No.	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage	Per segment Per decimal point	V _F	GL3T422 GL3T421 I _F = 10mA	—	1.7	2.2	V
			GL3T422 GL3T421 I _F = 10mA	—	1.7	2.2	V
*5 Luminous intensity	Per segment Per decimal point	I _V	GL3T422 GL3T421 I _F = 10mA	0.6	1.5	—	mcad
			GL3T422 GL3T421 I _F = 10mA	0.18	0.45	—	mcad
*2 Peak emission wavelength	λ _p	GL3T422 GL3T421	I _F = 10mA	—	660	—	nm
*2 Spectrum radiation bandwidth	Δλ	GL3T422 GL3T421	I _F = 10mA	20	—	—	nm
Reverse current	Per segment Per decimal point	I _R	GL3T422 GL3T421 V _R = 4V	—	10	—	μA
			GL3T422 GL3T421 V _R = 4V	—	—	10	μA
*2 Response frequency	f _c	GL3T422 GL3T421	—	—	8	—	MHz

*2 Per segment or per decimal point

*5 Tolerance: ±30%

Characteristics Diagrams